TOSHIBA Photocoupler GaAs Ired \& Photo-Transistor

## TLP121

## Office Machine

Programmable Controllers

## AC / DC-Input Module

## Telecommunication

The TOSHIBA mini flat coupler TLP121 is a small outline coupler, suitable for surface mount assembly.
TLP121 consists of a photo transistor, optically coupled to a gallium arsenide infrared emitting diode.

- Collector-emitter voltage: 80 V (min.)
- Current transfer ratio: $50 \%$ (min.)

Rank GB: 100\% (min.)

- Isolation voltage: 3750Vrms (min.)
- UL recognized: UL1577, file no. E67349


## Pin Configurations (top view)



Weight: 0.09 g

## Current Transfer Ratio

| Type | Classification *1 | $\begin{gathered} \hline \text { Current Transfer } \\ \text { Ratio (\%) } \\ \left(I_{c} / I_{F}\right) \\ \hline \end{gathered}$ |  | Marking Of Classification |
| :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ |  |  |
|  |  | Min. | Max. |  |
| TLP121 | (None) | 50 | 600 | BLANK, Y, Y", G, G', B, B', GB |
|  | Rank Y | 50 | 150 | Y, $\mathrm{Y}^{\mathbf{( 1}}$ |
|  | Rank GR | 100 | 300 | G, G' |
|  | - | 200 | 600 | B, $\mathrm{B}^{\prime \prime}$ |
|  | Rank GB | 100 | 600 | G, G', B, B', GB |

*1: Ex, rank GB: TLP121 (GB)
Note: Application type name for certification test, please use standard product type name, i, e. TLP121 (GB): TLP121

Maximum Ratings ( $\mathbf{T a}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ )

| Characteristic |  | Symbol | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: |
| 邑 | Forward current | $\mathrm{I}_{\mathrm{F}}$ | 50 | mA |
|  | Forward current derating | $\Delta \mathrm{I}_{\mathrm{F}} /{ }^{\circ} \mathrm{C}$ | $-0.7\left(\mathrm{Ta} \geq 53^{\circ} \mathrm{C}\right)$ | mA/ ${ }^{\circ} \mathrm{C}$ |
|  | Pulse forward current | $\mathrm{I}_{\text {FP }}$ | 1 (100 $\mu$ s pulse, 100pps) | A |
|  | Reverse voltage | $\mathrm{V}_{\mathrm{R}}$ | 5 | V |
|  | Junction temperature | $\mathrm{T}_{\mathrm{j}}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
|  | Collector-emitter voltage | $\mathrm{V}_{\text {CEO }}$ | 80 | V |
|  | Emitter-collector voltage | $V_{\text {ECO }}$ | 7 | V |
|  | Collector current | $\mathrm{I}_{C}$ | 50 | mA |
|  | Collector power dissipation | $\mathrm{P}_{\mathrm{C}}$ | 150 | mW |
|  | Collector power dissipation derating ( $\mathrm{Ta} \geq 25^{\circ} \mathrm{C}$ ) | $\Delta \mathrm{P}_{\mathrm{C}} /{ }^{\circ} \mathrm{C}$ | -1.5 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  | Junction temperature | $\mathrm{T}_{\mathrm{j}}$ | 125 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range |  | $\mathrm{T}_{\text {stg }}$ | -55~125 | ${ }^{\circ} \mathrm{C}$ |
| Operating temperature range |  | $\mathrm{T}_{\text {opr }}$ | -55~100 | ${ }^{\circ} \mathrm{C}$ |
| Lead soldering temperature |  | T ${ }_{\text {sol }}$ | 260 (10s) | ${ }^{\circ} \mathrm{C}$ |
| Total package power dissipation |  | $\mathrm{P}_{\mathrm{T}}$ | 200 | mW |
| Total package power dissipation derating ( $\mathrm{Ta} \geq 25^{\circ} \mathrm{C}$ ) |  | $\Delta \mathrm{P}_{\mathrm{T}} /{ }^{\circ} \mathrm{C}$ | -2.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| Isolation voltage (Note 1) |  | $\mathrm{BV}_{\mathrm{S}}$ | 3750 (AC, 1min., R.H. $\leq 60 \%$ ) | Vrms |

(Note 1) Device considered a two terminal device: Pins1, 3 shorted together and pins 4, 6 shorted together

## Recommended Operating Conditions

| Characteristic | Symbol | Min. | Typ. | Max. | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{CC}}$ | - | 5 | 48 | V |
| Forward current | $\mathrm{I}_{\mathrm{F}}$ | - | 16 | 20 | mA |
| Collector current | $\mathrm{I}_{\mathrm{C}}$ | - | 1 | 10 | mA |
| Operating temperature | $\mathrm{T}_{\mathrm{opr}}$ | -25 | - | 85 | ${ }^{\circ} \mathrm{C}$ |

Individual Electrical Characteristics ( $\mathbf{T a}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ )

| Characteristic |  | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| بـ | Forward voltage | $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | 1.0 | 1.15 | 1.3 | V |
|  | Reverse current | $\mathrm{I}_{\mathrm{R}}$ | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ | - | - | 10 | $\mu \mathrm{A}$ |
|  | Capacitance | $\mathrm{C}_{\text {T }}$ | $V=0, f=1 \mathrm{MHz}$ | - | 30 | - | pF |
| $\begin{aligned} & \grave{0} \\ & \text { O} \\ & \text { © } \\ & \hline 0 \end{aligned}$ | Collector-emitter breakdown voltage | $V_{(B R)}$ CEO | $\mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~mA}$ | 80 | - | - | V |
|  | Emitter-collector breakdown voltage | $V_{(B R) ~ E C O}$ | $\mathrm{I}_{\mathrm{E}}=0.1 \mathrm{~mA}$ | 7 | - | - | V |
|  | Collector dark current | ICEO | $\mathrm{V}_{\mathrm{CE}}=48 \mathrm{~V}$ | - | 10 | 100 | nA |
|  |  |  | $\mathrm{V}_{\text {CE }}=48 \mathrm{~V}, \mathrm{Ta}=85^{\circ} \mathrm{C}$ | - | 2 | 50 | $\mu \mathrm{A}$ |
|  | Capacitance (collector to emitter) | $\mathrm{C}_{\text {CE }}$ | $V=0, f=1 \mathrm{MHz}$ | - | 10 | - | pF |

Coupled Electrical Characteristics ( $\mathbf{T a}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Test Condition | MIn. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Current transfer ratio | $\mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ <br> Rank GB | 50 | - | 600600 | \% |
|  |  |  | 100 | - |  |  |
| Saturated CTR | $\mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{F}}$ (sat) | $\begin{array}{r} \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=0.4 \mathrm{~V} \\ \text { Rank } \mathrm{GB} \end{array}$ | - | 60 | - | \% |
|  |  |  | 30 | - | - |  |
| Collector-emitter saturation voltage | $\mathrm{V}_{\text {CE }}$ (sat) | $\mathrm{I}_{\mathrm{C}}=2.4 \mathrm{~mA}, \mathrm{I}_{\mathrm{F}}=8 \mathrm{~mA}$ | - | - | 0.4 | V |
|  |  | $\begin{array}{r} \mathrm{I}_{\mathrm{C}}=0.2 \mathrm{~mA}, \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA} \\ \text { Rank } \mathrm{GB} \end{array}$ | - | 0.2 | - |  |
|  |  |  | - | - | 0.4 |  |
| Off-state collector current | IC (off) | $\mathrm{V}_{\mathrm{F}}=0.7 \mathrm{~V}, \mathrm{~V}_{\mathrm{CE}}=48 \mathrm{~V}$ | - | 1 | 10 | $\mu \mathrm{A}$ |

Isolation Characteristics ( $\mathbf{T a}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Capacitance (input to output) | $\mathrm{C}_{S}$ | $\mathrm{V}_{\mathrm{S}}=0, \mathrm{f}=1 \mathrm{MHz}$ | - | 0.8 | - | pF |
| Isolation resistance | RS | $\mathrm{V}_{\mathrm{S}}=500 \mathrm{~V}$, R.H. $\leq 60 \%$ | $5 \times 10^{10}$ | $10^{14}$ | - | $\Omega$ |
| Isolation voltage | $B V_{S}$ | AC, 1 minute | 3750 | - | - | Vrms |
|  |  | AC, 1 second, in oil | - | 10000 | - |  |
|  |  | DC, 1 minute, in oil | - | 10000 | - | Vdc |

Switching Characteristics ( $\mathbf{T a}=25^{\circ} \mathrm{C}$ )

| Characteristic | Symbol | Test Condition |  | Min. | Typ. | Max. |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

Fig. 1 Switching time test circuit








$I_{C} / I_{F}-I_{F}$

Current transfer ratio $I_{C} / I_{F} \quad(\%)$


Collector-emitter voltage $\mathrm{V}_{\mathrm{CE}} \quad(\mathrm{V})$


Switching Time - RL

$\mathrm{IC}-\mathrm{Ta}$


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